

BTA316X series B, C and E

16 A Three-quadrant triacs high commutation Rev. 01 — 11 April 2007

Product data sheet

Product profile

1.1 General description

Passivated, new generation, high commutation triacs in a SOT186A isolated full pack plastic package

1.2 Features

- Very high commutation performance maximized at each gate sensitivity
- High isolation voltage
- High immunity to dV/dt
- Wide range of gate sensitivities

1.3 Applications

- High power motor control e.g. washing
 Refrigeration and air conditioning machines and vacuum cleaners
- Non-linear rectifier-fed motor loads.
- compressors
- Electronic thermostats

1.4 Quick reference data

- $V_{DRM} \le 600 \text{ V (BTA316X-600B/C/E)}$
- $V_{DRM} \le 800 \text{ V (BTA316X-800B/C/E)}$
- $I_{TSM} \le 140 \text{ A (t = 20 ms)}$
- $I_{T(RMS)} \le 16 A$

- I_{GT} \leq 50 mA (BTA316X series B)
- $I_{GT} \le 35 \text{ mA (BTA316X series C)}$
- I_{GT} ≤ 10 mA (BTA316X series E)

Pinning information

Table 1 Dinning

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		
2	main terminal 2 (T2)	mb	T2—T1
3	gate (G)		sym051
mb	mounting base; isolated		
		SOT186A (TO-220F))



3. Ordering information

Table 2. Ordering information

Type number	Package										
	Name Description										
BTA316X-600B	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole;	SOT186A								
BTA316X-600C		3-lead TO-220 'full pack'									
BTA316X-600E											
BTA316X-800B											
BTA316X-800C											
BTA316X-800E											

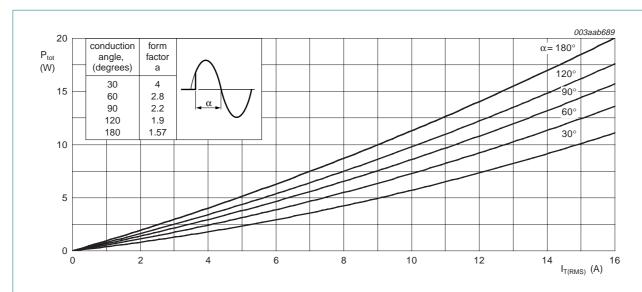
4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

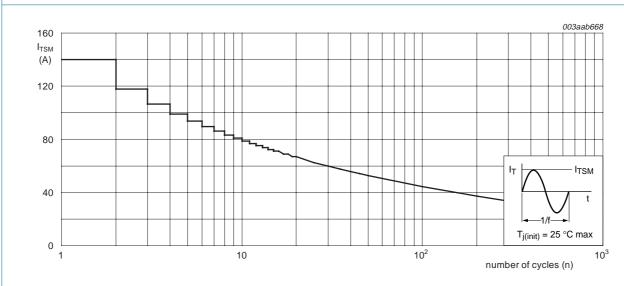
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage	BTA316X-600B; BTA316X-600C; BTA316X-600E	<u>[1]</u> -	600	V
		BTA316X-800B; BTA316X-800C; BTA316X-800E	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 45$ °C; see Figure 4 and 5	-	16	Α
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25$ °C prior to surge; see Figure 2 and 3			
		t = 20 ms	-	140	Α
		t = 16.7 ms	-	150	А
I ² t	I ² t for fusing	t = 10 ms	-	98	A^2s
dI _T /dt	rate of rise of on-state current	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	100	A/μs
I _{GM}	peak gate current		-	2	Α
P_GM	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

^[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.



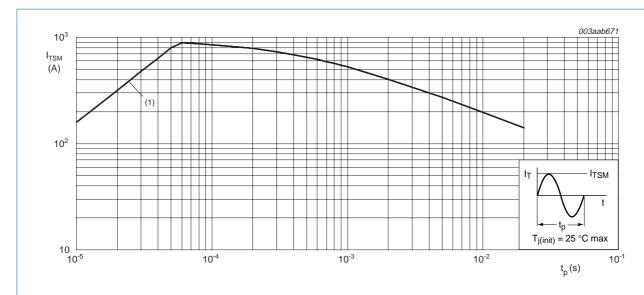
 α = conduction angle

Fig 1. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



 $t_p \le 20 \text{ ms}$

(1) dl_T/dt limit

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values

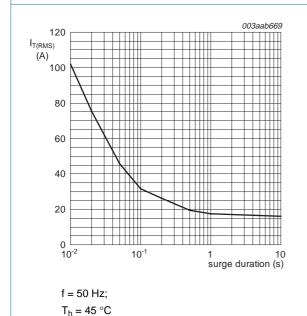


Fig 4. RMS on-state current as a function of surge duration; maximum values

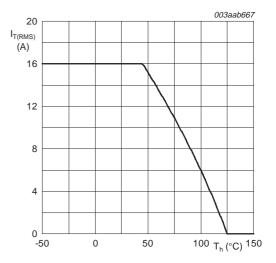
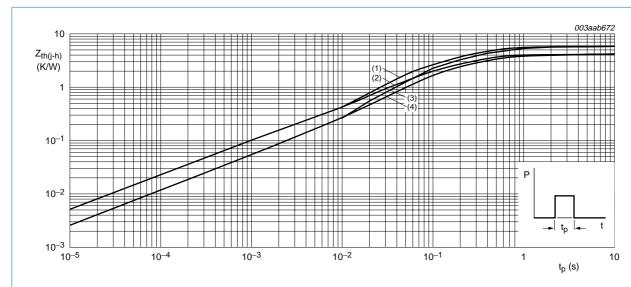


Fig 5. RMS on-state current as a function of heatsink temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	full or half cycle without heatsink compound; see Figure 6	-	-	5.5	K/W
		full or half cycle with heatsink compound; see Figure 6	-	-	4.0	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W



- (1) Unidirectional (half cycle) without heatsink compound
- (2) Unidirectional (half cycle) with heatsink compound
- (3) Bidirectional (full cycle) without heatsink compound
- (4) Bidirectional (full cycle) with heatsink compound

Fig 6. Transient thermal impedance from junction to heatsink as a function of pulse duration

6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

 $T_h = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all three terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; RH ≤ 65 %; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from pin 2 to external heatsink; f = 1 MHz	-	10	-	pF

7. Static characteristics

Table 6. Static characteristics

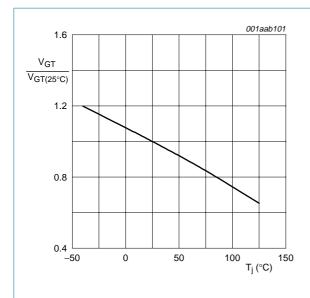
 $T_i = 25 \,^{\circ}C$ unless otherwise specified.

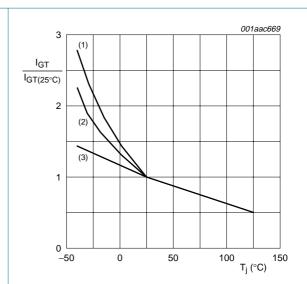
Symbol	Parameter	Conditions		A316X-0 A316X-0			A316X- A316X-			A316X-6 A316X-8		Unit
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
I _{GT}	gate trigger current	$V_D = 12 V;$ $I_T = 0.1 A;$ see Figure 8										
		T2+ G+	2	-	50	2	-	35	-	-	10	mΑ
		T2+ G-	2	-	50	2	-	35	-	-	10	mA
		T2- G-	2	-	50	2	-	35	-	-	10	mΑ
I _L latching current		$V_D = 12 V;$ $I_{GT} = 0.1 A;$ see <u>Figure 10</u>										
		T2+ G+	-	-	60	-	-	50	-	-	25	mΑ
		T2+ G-	-	-	90	-	-	60	-	-	30	mΑ
		T2- G-	-	-	60	-	-	50	-	-	30	mΑ
I _H	holding current	$V_D = 12 \text{ V};$ $I_{GT} = 0.1 \text{ A};$ see Figure 11	-	-	60	-	-	35	-	-	15	mA
V_{T}	on-state voltage	I _T = 18 A; see <u>Figure 9</u>	-	1.3	1.5	-	1.3	1.5	-	1.3	1.5	V
V_{GT}	gate trigger voltage	$V_D = 12 V;$ $I_T = 0.1 A;$ see <u>Figure 7</u>	-	0.8	1.5	-	0.8	1.5	-	0.8	1.5	V
		$V_D = 400 \text{ V};$ $I_T = 0.1 \text{ A};$ $T_j = 125 \text{ °C}$	0.25	0.4	-	0.25	0.4	-	0.25	0.4	-	V
I _D	off-state current	$V_D = V_{DRM(max)};$ $T_j = 125 ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	-	0.1	0.5	mA

8. Dynamic characteristics

Table 7. Dynamic characteristics

Symbol	Parameter	Conditions		316X-6 316X-8			4316X-6 4316X-8		BT/	Unit		
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
dV _D /dt	rate of rise of off-state voltage	$\begin{split} &V_{DM} = 0.67 \times \\ &V_{DRM(max)}; \\ &T_{j} = 125 ^{\circ}\text{C}; \\ &\text{exponential} \\ &\text{waveform; gate open} \\ &\text{circuit} \end{split}$	1000	-	-	500	-	-	60	-	-	V/µs
dl _{com} /dt rate of chan of commutatin current		$V_{DM} = 400 \text{ V};$ $T_j = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 16 \text{A};$ without snubber; gate open circuit	20	-	-	15	-	-	5	-	-	A/ms
		$\begin{split} &V_{DM} = 400 \text{ V;} \\ &T_j = 125 \text{ °C;} \\ &I_{T(RMS)} = 16 \text{ A;} \\ &dV/dt = 10 \text{ V/}\mu\text{s;} \\ &\text{gate open circuit} \end{split}$	-	-	-	-	-	-	8	-	-	A/ms
		V_{DM} = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 16 A; dV/dt = 1 V/ μ s; gate open circuit	-	-	-	-	-	-	12	-	-	A/ms
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 20 \text{ A;} \\ V_D &= V_{DRM(max)}; \\ I_G &= 0.1 \text{ A;} \\ dI_G/dt &= 5 \text{ A/}\mu\text{s} \end{split}$	-	2	-	-	2	-	-	2	-	μs

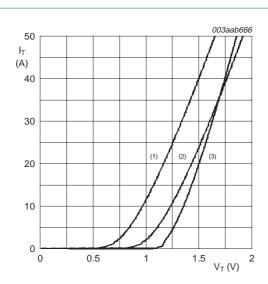




- (1) T2-G-
- (2) T2+ G-
- (3) T2+ G+

Fig 7. Normalized gate trigger voltage as a function of junction temperature

Fig 8. Normalized gate trigger current as a function of junction temperature



 $V_0 = 1.024 \text{ V}$

 $R_s = 0.021 \Omega$

- (1) $T_i = 125 \,^{\circ}\text{C}$; typical values
- (2) $T_j = 125$ °C; maximum values
- (3) $T_j = 25$ °C; maximum values

Fig 9. On-state current as a function of on-state voltage

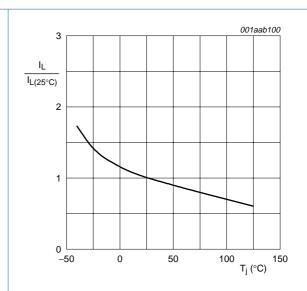


Fig 10. Normalized latching current as a function of junction temperature

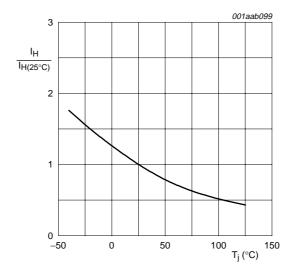


Fig 11. Normalized holding current as a function of junction temperature

9. Package information

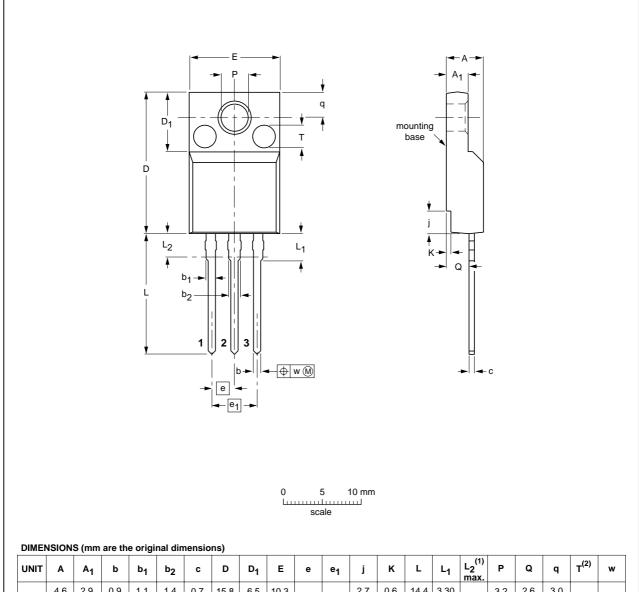
Epoxy meets UL94 V-0 at 3.175 mm

10. Package outline

Plastic single-ended package; isolated heatsink mounted;

1 mounting hole; 3-lead TO-220 'full pack'

SOT186A



UN	IT	Α	A ₁	b	b ₁	b ₂	С	D	D ₁	E	е	e ₁	j	к	L	L ₁	L ₂ ⁽¹⁾ max.	Р	Q	q	T ⁽²⁾	w
mı	n	4.6 4.0	2.9 2.5	0.9 0.7	1.1 0.9	1.4 1.0	0.7 0.4	15.8 15.2	6.5 6.3	10.3 9.7	2.54	5.08	2.7 1.7	0.6 0.4	14.4 13.5	3.30 2.79	3	3.2 3.0	2.6 2.3	3.0 2.6	2.5	0.4

- 1. Terminal dimensions within this zone are uncontrolled.
- 2. Both recesses are \varnothing 2.5 \times 0.8 max. depth

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT186A		3-lead TO-220F				02-04-09 06-02-14	

Fig 12. Package outline SOT186A (TO-220F)

BTA316X series B, C and E

16 A Three-quadrant triacs high commutation

11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA316X_SER_B_C_E_1	20070411	Product data sheet	-	-

BTA316X series B, C and E

16 A Three-quadrant triacs high commutation

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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